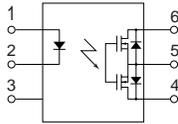
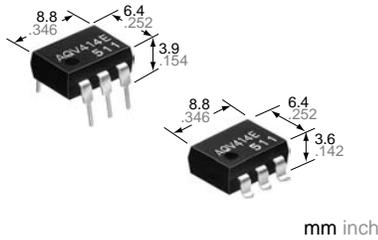


Normally closed DIP6-pin economic type with reinforced insulation

PhotoMOS Relays

GU-E 1 Form B

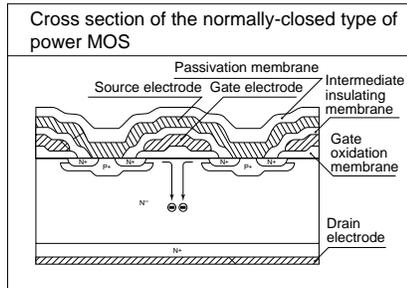
(AQV414E, AQV410EH)



Compliance with RoHS Directive

FEATURES

- High cost-performance type of PhotoMOS relay 1 Form B output**
- 60V type couples high capacity (0.55A) with low on-resistance (typ. 1Ω).**
- Low on-resistance**
This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



- Controls low-level analog signals**
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

- High sensitivity and low on-resistance**
Can control max. 0.55 A load current with 5 mA input current.
Low on-resistance of typ. 1Ω (AQV412EH).
- Low-level off-state leakage current of max. 1 μA (AQV414E)**
- Reinforced insulation 5,000 V type also available**
More than 0.4 mm internal insulation distance between inputs and outputs.
Conforms to EN41003, EN60950 (reinforced insulation).

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Telephone equipment
- Sensing equipment

TYPES

| | I/O isolation voltage | Output rating* | | Package | Part No. | | | | Packing quantity | |
|----------------|-------------------------|----------------|-----------------------|----------|--------------------------|-----------------------------|--------------------------------|------|--|------------|
| | | Load voltage | Load current | | Through hole terminal | Surface-mount terminal | | Tube | Tape and reel | |
| | | | | | | Tape and reel packing style | | | | |
| AC/DC dual use | 1,500 V AC (Standard) | 400 V | 120 mA | DIP6-pin | Tube packing style | | Picked from the 1/2/3-pin side | | 1 tube contains: 50 pcs. 1 batch contains: 500 pcs. | 1,000 pcs. |
| | | | | | AQV414E AQV414EA | | AQV414EAX AQV414EAZ | | | |
| | 60 V 550 mA | | AQV412EH AQV412EHA | | AQV412EHAX AQV412EHAZ | | | | | |
| | 350 V 130 mA | | AQV410EH AQV410EHA | | AQV410EHAX AQV410EHAZ | | | | | |
| | 5,000 V AC (Reinforced) | 400 V | 120 mA | | AQV414EH AQV414EHA | | AQV414EHAX AQV414EHAZ | | | |

*Indicate the peak AC and DC values.
Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

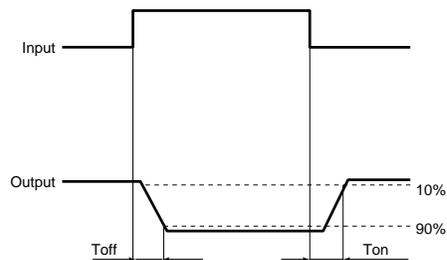
| Item | Symbol | Type of connection | AQV414E(A) | AQV412EH(A) | AQV410EH(A) | AQV414EH(A) | Remarks | |
|-------------------------|-------------------------|--------------------|---------------------------------|-------------|-------------|-------------|--|---|
| Input | LED forward current | I _F | 50 mA | | | | | |
| | LED reverse voltage | V _R | 5 V | | | | | |
| | Peak forward current | I _{FP} | 1 A | | | | f = 100 Hz, Duty factor = 0.1% | |
| | Power dissipation | P _{in} | 75 mW | | | | | |
| Output | Load voltage (peak AC) | V _L | 400 V | 60 V | 350 V | 400 V | | |
| | Continuous load current | I _L | A | 0.12 A | 0.55 A | 0.13 A | 0.12 A | A connection: Peak AC, DC B,C connection: DC |
| | | | B | 0.13 A | 0.65 A | 0.15 A | 0.13 A | |
| | | | C | 0.15 A | 0.8 A | 0.17 A | 0.15 A | |
| | Peak load current | I _{peak} | 0.3 A | 1.5 A | 0.4 A | 0.3 A | A connection: 100 ms (1 shot), V _L = DC | |
| Power dissipation | P _{out} | 500 mW | | | | | | |
| Total power dissipation | P _T | 550 mW | | | | | | |
| I/O isolation voltage | V _{iso} | | 1,500 V AC | 5,000 V AC | | | | |
| Temperature limits | Operating | T _{opr} | -40°C to +85°C -40°F to +185°F | | | | Non-condensing at low temperatures | |
| | Storage | T _{stg} | -40°C to +100°C -40°F to +212°F | | | | | |

GU-E 1 Form B (AQV414E, AQV410EH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

| Item | | Symbol | Type of connection | AQV414E(A) | AQV412EH(A) | AQV410EH(A) | AQV414EH(A) | Condition | |
|----------------------------------|---------------------------|---------------------|--------------------|--|-------------|-------------|-------------|--|--|
| Input | LED operate (OFF) current | Typical | I _{off} | — | 1.45 mA | 1.9 mA | | I _L = Max. | |
| | | Maximum | | | 3.0 mA | | | | |
| | LED reverse (ON) current | Minimum | I _{on} | — | 0.3 mA | 0.4 mA | | I _L = Max. | |
| | | Typical | | | 1.40 mA | | | | |
| LED dropout voltage | Typical | V _F | — | 1.25 V (1.14 V at I _F = 5 mA) | | | | I _F = 50 mA | |
| | Maximum | | | 1.5 V | | | | | |
| Output | On resistance | Typical | R _{on} | A | 26 Ω | 1 Ω | 18 Ω | 25.2 Ω | I _F = 0 mA I _L = Max. Within 1 s on time |
| | | Maximum | | | 50 Ω | 2.5 Ω | 35 Ω | 50 Ω | |
| | | Typical | R _{on} | B | 20 Ω | 0.55 Ω | 13 Ω | 19 Ω | |
| | | Maximum | | | 25 Ω | 1.3 Ω | 17.5 Ω | 25 Ω | |
| | Typical | R _{on} | C | 10 Ω | 0.3 Ω | 6.5 Ω | 10 Ω | I _F = 0 mA I _L = Max. Within 1 s on time | |
| | Maximum | | | 12.5 Ω | 0.7 Ω | 8.8 Ω | 12.5 Ω | | |
| | Off state leakage current | Maximum | I _{Leak} | — | 1 μA | 10 μA | | I _F = 5 mA V _L = Max. | |
| | Transfer characteristics | Operate (OFF) time* | Typical | T _{off} | — | 0.7 ms | 3 ms | 1.5 ms | 1.3 ms |
| Maximum | | | 2.0 ms | | | 8 ms | 3.0 ms | | |
| Reverse (ON) time* | | Typical | T _{on} | — | 0.1 ms | 0.3 ms | | | I _F = 5 mA → 0 mA I _L = Max. |
| | | Maximum | | | 1.0 ms | 1.5 ms | | | |
| I/O capacitance | | Typical | C _{iso} | — | 0.8 pF | | | | f = 1 MHz V _B = 0 V |
| | Maximum | 1.5 pF | | | | | | | |
| Initial I/O isolation resistance | Minimum | R _{iso} | — | 1,000 MΩ | | | 500 V DC | | |

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

| Item | Symbol | Recommended value | Unit |
|-------------------|----------------|--|------|
| Input LED current | I _F | Standard type: 5 Reinforced type: 5 to 10 | mA |

- For Dimensions
- For Schematic and Wiring Diagrams
- For Cautions for Use

■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Electric Works technical representative.

For more information

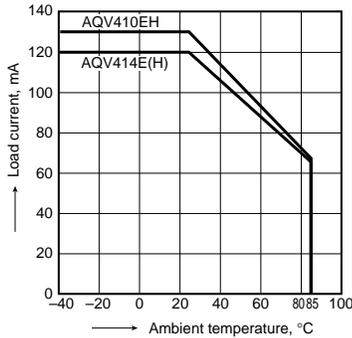
GU-E 1 Form B (AQV414E, AQV410EH)

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

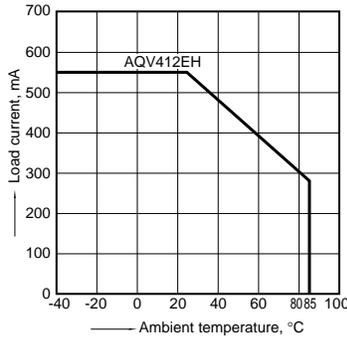
Type of connection: A



1-(2). Load current vs. ambient temperature characteristics

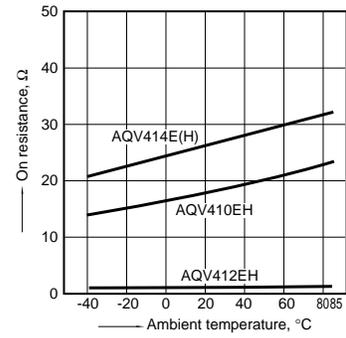
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



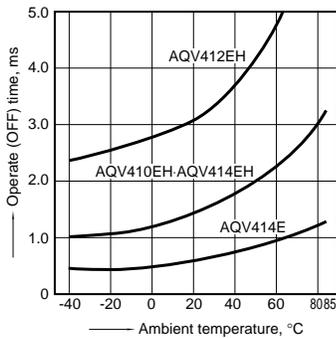
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



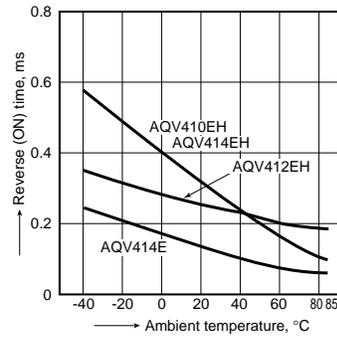
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



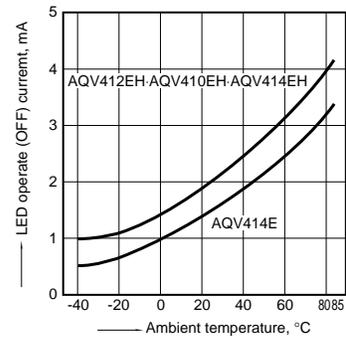
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



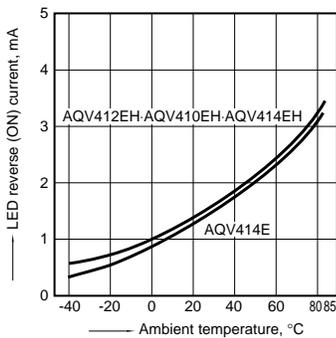
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



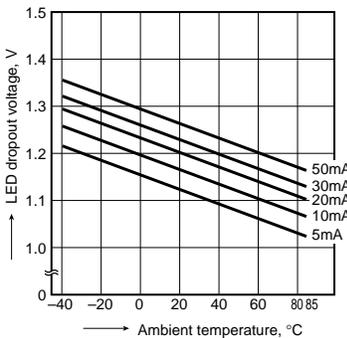
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



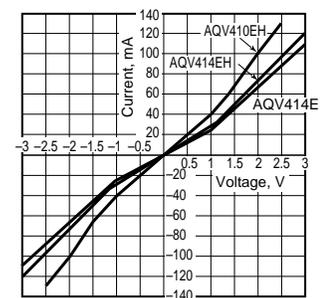
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
LED current: 5 to 50 mA



8-(1). Current vs. voltage characteristics of output at MOS portion

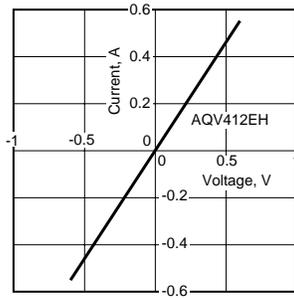
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



GU-E 1 Form B (AQV414E, AQV410EH)

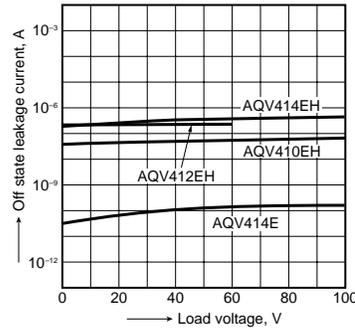
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



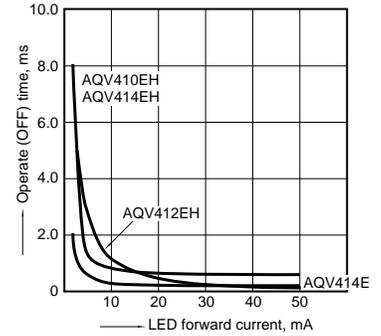
9. Off state leakage current vs. load voltage characteristics

Sample: All types;
Measured portion: between terminals 4 and 6;
LED current: 5 mA; Ambient temperature: 25°C 77°F



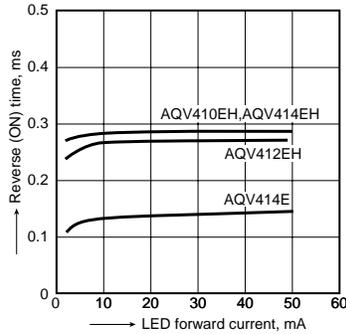
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

